

Fault-Protected RS-485 Transceivers with 3.3-V to 5-V Operation

Check for Samples: [SN65HVD1780-Q1](#), [SN65HVD1781-Q1](#), [SN65HVD1782 -Q1](#)

FEATURES

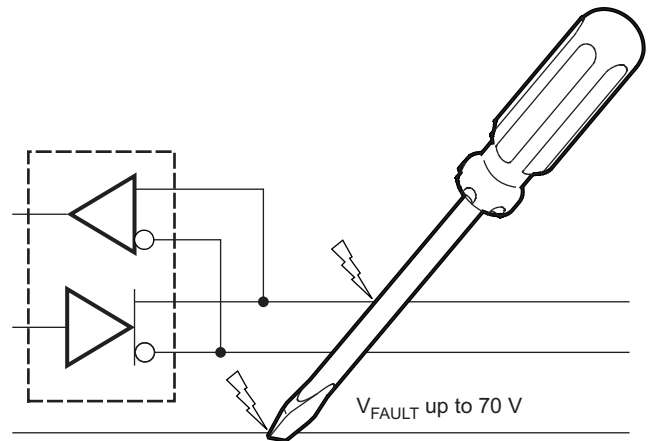
- **Qualified for Automotive Applications**
- **Bus-Pin Fault Protection to:**
 - $> \pm 70\text{ V}$ ('HVD1780, 81)
 - $> \pm 30\text{ V}$ ('HVD1782)
- **Operation With 3.3-V to 5-V Supply Range**
- **$\pm 16\text{ kV}$ HBM Protection on Bus Pins**
- **Reduced Unit Load for up to 320 Nodes**
- **Failsafe Receiver for Open-Circuit, Short-Circuit and Idle-Bus Conditions**
- **Low Power Consumption**
 - **Low Standby Supply Current, $1\text{ }\mu\text{A}$ Max**
 - **I_{CC} 4 mA Quiescent During Operation**
- **Pin-Compatible With Industry-Standard SN75176**
- **Signaling Rates of 115 kbps, 1 Mbps, and up to 10 Mbps**

DESCRIPTION

These devices are designed to survive overvoltage faults such as direct shorts to power supplies, mis-wiring faults, connector failures, cable crushes, and tool mis-applications. They are also robust to ESD events, with high levels of protection to the human-body-model specification.

These devices combine a differential driver and a differential receiver, which operate from a single power supply. In the 'HVD1782, the driver differential outputs and the receiver differential inputs are connected internally to form a bus port suitable for half-duplex (two-wire bus) communication. This port features a wide common-mode voltage range, making the devices suitable for multipoint applications over long cable runs. These devices are characterized from -40°C to 125°C . These devices are pin-compatible with the industry-standard SN75176 transceiver, making them drop-in upgrades in most systems.

These devices are fully compliant with ANSI TIA/EIA 485-A with a 5-V supply and can operate with a 3.3-V supply with reduced driver output voltage for low-power applications. For applications where operation is required over an extended common-mode voltage range, see the SN65HVD1785 ([SLLS872](#)) data sheet.



M0092-02

Transceiver	Signaling Rate	Number of Nodes
HVD1780	Up to 115 kbps	Up to 320
HVD1781	Up to 1 Mbps	Up to 320
HVD1782	Up to 10 Mbps	Up to 64



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2010, Texas Instruments Incorporated

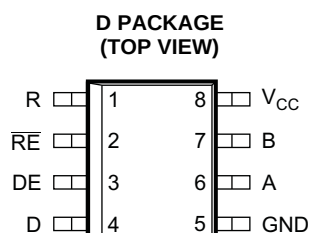


These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

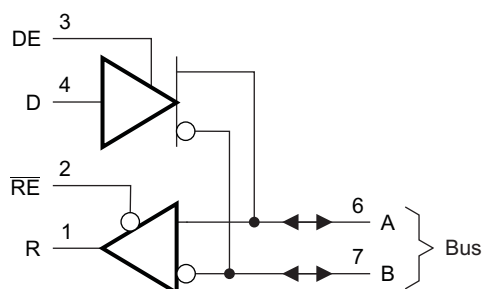
ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC – D	Reel of 2500	SN65HVD1780QDRQ1 ⁽³⁾	Product Preview
			SN65HVD1781QDRQ1	1781Q
			SN65HVD1782QDRQ1 ⁽³⁾	Product Preview

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
 (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
 (3) Product Preview



LOGIC DIAGRAM (POSITIVE LOGIC)



S0299-02

DEVICE INFORMATION

DRIVER FUNCTION TABLE

Input	Enable	Outputs		Driver State
D	DE	A	B	
H	H	H	L	Actively drive bus High
L	H	L	H	Actively drive bus Low
X	L	Z	Z	Driver disabled ⁽¹⁾
X	OPEN	Z	Z	Driver disabled by default ⁽¹⁾
OPEN	H	H	L	Actively drive bus High by default

- (1) When both the driver and receiver are disabled, the device enters a low-power standby mode.

RECEIVER FUNCTION TABLE

Differential Input	Enable	Output	Receiver State
V _{ID} = V _A – V _B	RE	R	
V _{IT+} < V _{ID}	L	H	Receive valid bus High
V _{IT–} < V _{ID} < V _{IT+}	L	?	Indeterminate bus state
V _{ID} < V _{IT–}	L	L	Receive valid bus Low
X	H	Z	Receiver disabled ⁽¹⁾
X	OPEN	Z	Receiver disabled by default ⁽¹⁾
Open-circuit bus	L	H	Fail-safe high output
Short-circuit bus	L	H	Fail-safe high output
Idle (terminated) bus	L	H	Fail-safe high output

- (1) When both the driver and receiver are disabled, the device enters a low-power standby mode.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

				VALUE	UNIT	
V _{CC}	Supply voltage			–0.5 to 7	V	
Voltage range at bus pins			'HVD1780, 81	A, B pins	–70 to 70	V
			'HVD1782	A, B pins	–70 to 30	
Input voltage range at any logic pin				–0.3 to V _{CC} + 0.3	V	
Transient overvoltage pulse through 100 Ω per TIA-485				–70 to 70	V	
Receiver output current				–24 to 24	mA	
T _J	Junction temperature			170	°C	
Continuous total power dissipation				See Dissipation Rating Table		
ESD	Electrostatic discharge	Human-Body Model (HBM), IEC 60749-26.		Bus terminals and GND	±16	kV
		Human-Body Model (HBM). Test method based upon AEC-Q100-002		Bus terminals and GND	±16	kV
		Human-Body Model (HBM), AEC-Q100-002		All Pins	±4	kV
		Charged-Device Model (CDM), AEC-Q100-011		All Pins	±2	kV
		Machine Model (MM) , AEC-Q100-003		All Pins	±400	V

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

PACKAGE DISSIPATION RATINGS

PACKAGE ⁽¹⁾	JEDEC THERMAL MODEL	T _A < 25°C RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 85°C RATING	T _A = 105°C RATING	T _A = 125°C RATING (3.3 V ONLY)
SOIC (D) 8-pin	High-K	905 mW	7.25 mW/°C	470 mW	325 mW	180 mW
	Low-K	516 mW	4.1 mW/°C	268 mW	186 mW	103 mW

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

RECOMMENDED OPERATING CONDITIONS

				MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage			3.15	5	5.5	V
V _I	Input voltage at any bus terminal (separately or common mode) ⁽¹⁾			–7		12	V
V _{IH}	High-level input voltage (driver, driver enable, and receiver enable inputs)			2		V _{CC}	V
V _{IL}	Low-level input voltage (driver, driver enable, and receiver enable inputs)			0		0.8	V
V _{ID}	Differential input voltage			–12		12	V
I _O	Output current, driver			–60		60	mA
	Output current, receiver			–8		8	mA
R _L	Differential load resistance			54	60		Ω
C _L	Differential load capacitance				50		pF
1/t _{UI}	Signaling rate	HVD1780				115	Mbps
		HVD1781				1	
		HVD1782				10	
T _A	Operating free-air temperature (See application section for thermal information)	5-V supply		–40		105	°C
		3.3-V supply		–40		125	
T _J	Junction Temperature			–40		150	

- (1) By convention, the least positive (most negative) limit is designated as minimum in this data sheet.

ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{OD}	Driver differential output voltage magnitude	R _L = 60 Ω, 4.75 V ≤ V _{CC} 375 Ω on each output to –7 V to 12 V Figure 1		T _A < 85°C	1.5			V
				T _A < 125°C	1.4			
		R _L = 54 Ω, 4.75 V ≤ V _{CC} ≤ 5.25 V		T _A < 85°C	1.7	2		
				T _A < 125°C	1.5			
		R _L = 54 Ω, 3.15 V ≤ V _{CC} ≤ 3.45 V			0.8	1		
		R _L = 100 Ω, 4.75 V ≤ V _{CC} ≤ 5.25 V		T _A < 85°C	2.2	2.5		
T _A < 125°C	2							
Δ V _{OD}	Change in magnitude of driver differential output voltage	R _L = 54 Ω			–50	0	50	mV
V _{OC(SS)}	Steady-state common-mode output voltage				1	V _{CC} /2	3	V
ΔV _{OC}	Change in differential driver output common-mode voltage				–50	0	50	mV
V _{OC(PP)}	Peak-to-peak driver common-mode output voltage	Center of two 27-Ω load resistors, See Figure 2				500		mV
C _{OD}	Differential output capacitance					23		pF
V _{IT+}	Positive-going receiver differential input voltage threshold					–100	–35	mV
V _{IT–}	Negative-going receiver differential input voltage threshold					–180	–150	
V _{HYS}	Receiver differential input voltage threshold hysteresis (V _{IT+} – V _{IT–}) ⁽¹⁾					30	50	
V _{OH}	Receiver high-level output voltage	I _{OH} = –8 mA			2.4	V _{CC} – 0.3		V
V _{OL}	Receiver low-level output voltage	I _{OL} = 8 mA	T _A < 85°C		0.2	0.4	V	
			T _A < 125°C			0.5		
I _{I(LOGIC)}	Driver input, driver enable, and receiver enable input current				–50		50	μA
I _{OZ}	Receiver output high-impedance current	V _O = 0 V or V _{CC} , $\overline{\text{RE}}$ at V _{CC}			–1		1	μA
I _{OS}	Driver short-circuit output current				–200		200	mA
I _{I(BUS)}	Bus input current (disabled driver)	V _{CC} = 3.15 to 5.5 V or V _{CC} = 0 V, DE at 0 V	V _I = 12 V	1780, 1781	75	100	μA	
				1782	400	500		
			V _I = –7 V	1780, 1781	–60	–40		
				1782	–400	–300		
I _{CC}	Supply current (quiescent)	Driver and receiver enabled	DE = V _{CC} , RE = GND, no load		4	6	mA	
		Driver enabled, receiver disabled	DE = V _{CC} , RE = V _{CC} , no load		3	5		
		Driver disabled, receiver enabled	DE = GND, RE = GND, no load		2	4		
		Driver and receiver disabled, standby mode	DE = GND, D = open, RE = V _{CC} , no load, T _A < 85°C		0.15	1	μA	
			DE = GND, D = open, RE = V _{CC} , no load, T _A < 125°C			12		
		Supply current (dynamic)		See the Typical Characteristics section				

(1) Ensured by design. Not production tested.

SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
DRIVER (HVD1780)							
t_r, t_f	Driver differential output rise/fall time	$R_L = 54 \, \Omega, C_L = 50 \, \text{pF}$, See Figure 3	$3.15 \, \text{V} < V_{CC} < 3.45 \, \text{V}$	0.4	1.4	1.8	μs
t_{PHL}, t_{PLH}	Driver propagation delay		$3.15 \, \text{V} < V_{CC} < 5.5 \, \text{V}$	0.4	1.7	2.6	μs
$t_{SK(P)}$	Driver differential output pulse skew, $ t_{PHL} - t_{PLH} $				0.8	2	μs
t_{PHZ}, t_{PLZ}	Driver disable time				20	250	ns
t_{PZH}, t_{PZL}	Driver enable time	Receiver enabled	See Figure 4 and Figure 5		0.1	5	μs
		Receiver disabled			0.2	3	μs
					3	12	
DRIVER (HVD1781)							
t_r, t_f	Driver differential output rise/fall time	$R_L = 54 \, \Omega, C_L = 50 \, \text{pF}$, See Figure 3		50		300	ns
t_{PHL}, t_{PLH}	Driver propagation delay					200	ns
$t_{SK(P)}$	Driver differential output pulse skew, $ t_{PHL} - t_{PLH} $					25	ns
t_{PHZ}, t_{PLZ}	Driver disable time		See Figure 4 and Figure 5			3	μs
t_{PZH}, t_{PZL}	Driver enable time	Receiver enabled				300	ns
		Receiver disabled				10	μs
DRIVER (HVD1782)							
t_r, t_f	Driver differential output rise/fall time	$R_L = 54 \, \Omega, C_L = 50 \, \text{pF}$	All V_{CC} and Temp			50	ns
			$V_{CC} > 4.5\text{V}$ and $T < 105^\circ\text{C}$		16		
t_{PHL}, t_{PLH}	Driver propagation delay					55	ns
$t_{SK(P)}$	Driver differential output pulse skew, $ t_{PHL} - t_{PLH} $		See Figure 3			10	ns
t_{PHZ}, t_{PLZ}	Driver disable time					3	μs
t_{PZH}, t_{PZL}	Driver enable time	Receiver enabled	See Figure 4 and Figure 5			300	ns
		Receiver disabled				9	μs
RECEIVER (ALL DEVICES UNLESS OTHERWISE NOTED)							
t_r, t_f	Receiver output rise/fall time ⁽¹⁾	$C_L = 15 \, \text{pF}$, See Figure 6	All devices		4	15	ns
t_{PHL}, t_{PLH}	Receiver propagation delay time		HVD1780, HVD1781		100	200	ns
			HVD1782			80	
$t_{SK(P)}$	Receiver output pulse skew, $ t_{PHL} - t_{PLH} $		HVD1780, HVD1781		6	20	ns
			HVD1782			5	
t_{PLZ}, t_{PHZ}	Receiver disable time ⁽¹⁾	Driver enabled, See Figure 7			15	100	ns
$t_{PZL(1)}, t_{PZH(1)}$ $t_{PZL(2)}, t_{PZH(2)}$	Receiver enable time	Driver enabled, See Figure 7			80	300	ns
		Driver disabled, See Figure 8			3	9	μs

(1) Ensured by design. Not production tested.

THERMAL INFORMATION

PARAMETER		TEST CONDITIONS	VALUE	UNIT
R _{θJA}	Junction-to-ambient thermal resistance (no airflow)	SOIC-8 JEDEC high-K model JEDIC low-K model	138	°C/W
			242	
R _{θJB}	Junction-to-board thermal resistance	SOIC-8	62	°C/W
R _{θJC}	Junction-to-case thermal resistance	SOIC-8	61	°C/W
P _D	Power dissipation	V _{CC} = 3.6V, T _J = 150°C, R _L = 300 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 3.3-V supply, unterminated ⁽¹⁾	75	mW
		V _{CC} = 3.6V, T _J = 150°C, R _L = 100 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 3.3-V supply, RS-422 load ⁽¹⁾	95	
		V _{CC} = 3.6V, T _J = 150°C, R _L = 54 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 3.3-V supply, RS-485 load ⁽¹⁾	115	
		V _{CC} = 5.5V, T _J = 150°C, R _L = 300 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 5-V supply, unterminated ⁽¹⁾	290	
		V _{CC} = 5.5V, T _J = 150°C, R _L = 100 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 5-V supply, RS-422 load ⁽¹⁾	320	
		V _{CC} = 5.5V, T _J = 150°C, R _L = 54 Ω, C _L = 50 pF (driver), C _L = 15 pF (receiver) 5-V supply, RS-485 load ⁽¹⁾	400	
T _{SD}	Thermal-shutdown junction temperature		170	°C

(1) Driver and receiver enabled, 50% duty cycle square-wave signal at signaling rate: 1 Mbps.

APPLICATION INFORMATION

Hot-Plugging

These devices are designed to operate in "hot swap" or "hot pluggable" applications. Key features for hot-pluggable applications are power-up, power-down glitch free operation, default disabled input/output pins, and receiver failsafe. As shown in [Figure 9](#), an internal Power-On Reset circuit keeps the driver outputs in a high-impedance state until the supply voltage has reached a level at which the device will reliably operate. This ensures that no problems will occur on the bus pin outputs as the power supply turns on or turns off.

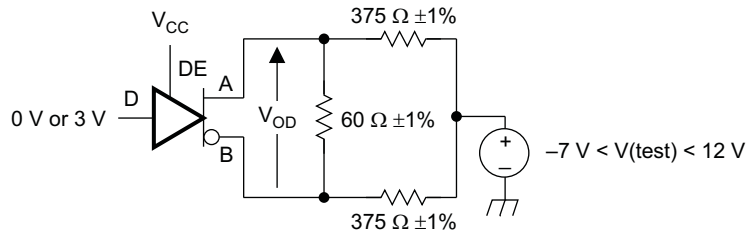
As shown in the device FUNCTION TABLE, the enable inputs have the feature of default disable on both the driver enable and receiver enable. This ensures that the device will neither drive the bus nor report data on the R pin until the associated controller actively drives the enable pins.

Receiver Failsafe

The differential receiver is "failsafe" to invalid bus states caused by open bus conditions such as, a disconnected connector, shorted bus conditions caused by damaged cabling, or idle bus conditions that occur when no driver is actively driving a valid RD-485 bus state on the network. In any of these cases, the differential receiver will output a failsafe HIGH state, so that small noise signals do not cause problems at the receiver output.

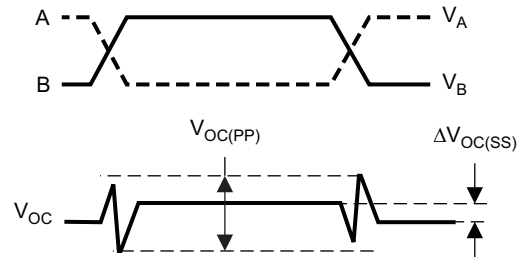
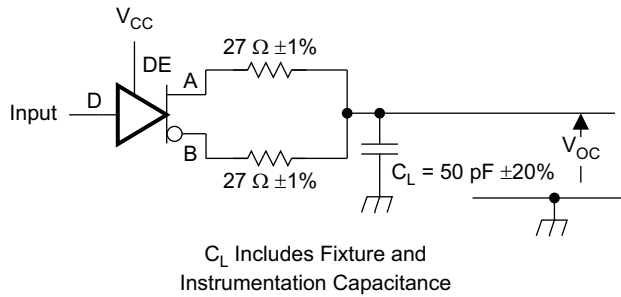
PARAMETER MEASUREMENT INFORMATION

Input generator rate is 100 kbps, 50% duty cycle, rise and fall times less than 6 nsec, output impedance 50 Ω .



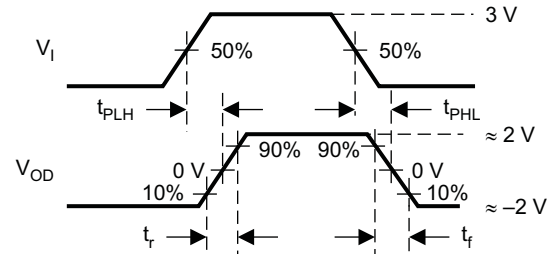
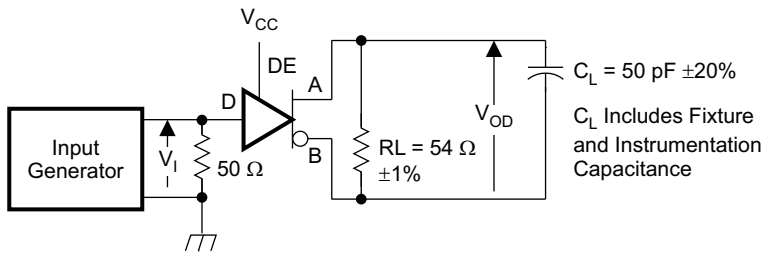
S0301-02

Figure 1. Measurement of Driver Differential Output Voltage With Common-Mode Load



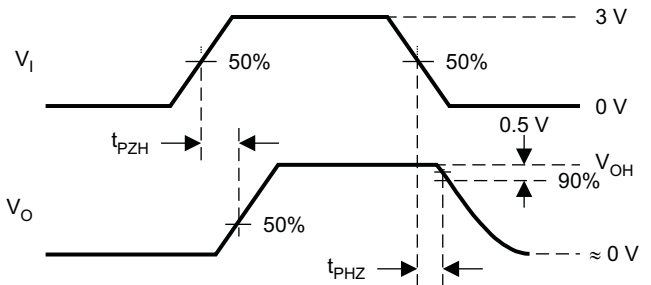
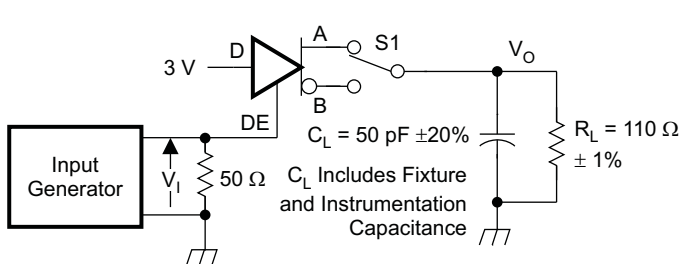
S0302-01

Figure 2. Measurement of Driver Differential and Common-Mode Output With RS-485 Load



S0303-01

Figure 3. Measurement of Driver Differential Output Rise and Fall Times and Propagation Delays

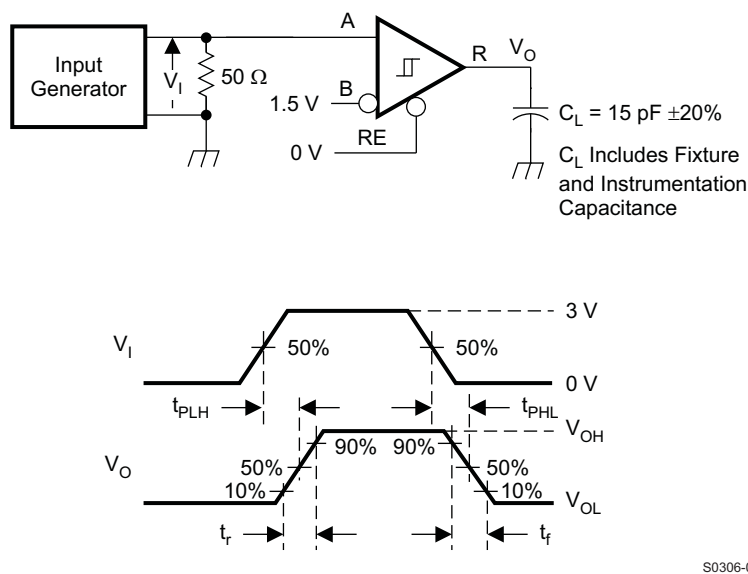
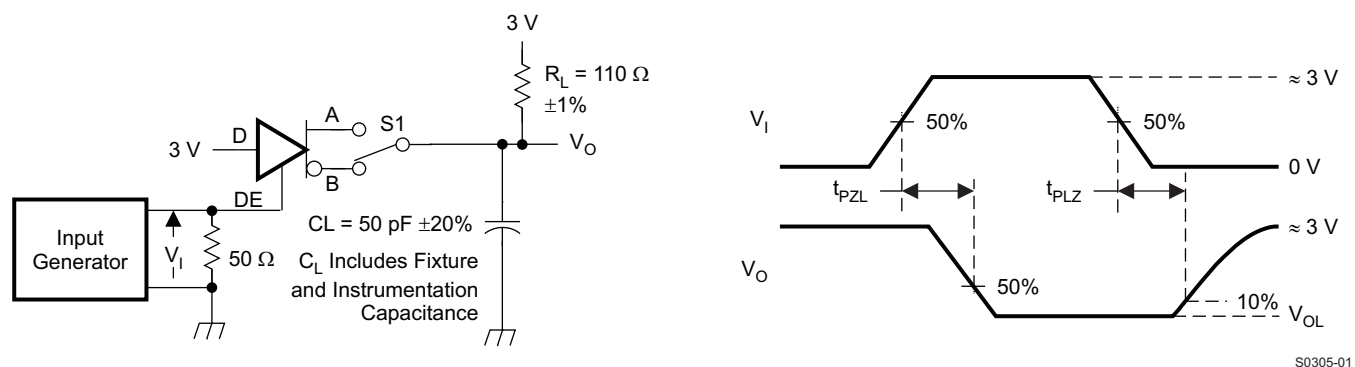


S0304-01

NOTE: D at 3 V to test non-inverting output, D at 0 V to test inverting output.

Figure 4. Measurement of Driver Enable and Disable Times With Active High Output and Pulldown Load

PARAMETER MEASUREMENT INFORMATION (continued)



PARAMETER MEASUREMENT INFORMATION (continued)

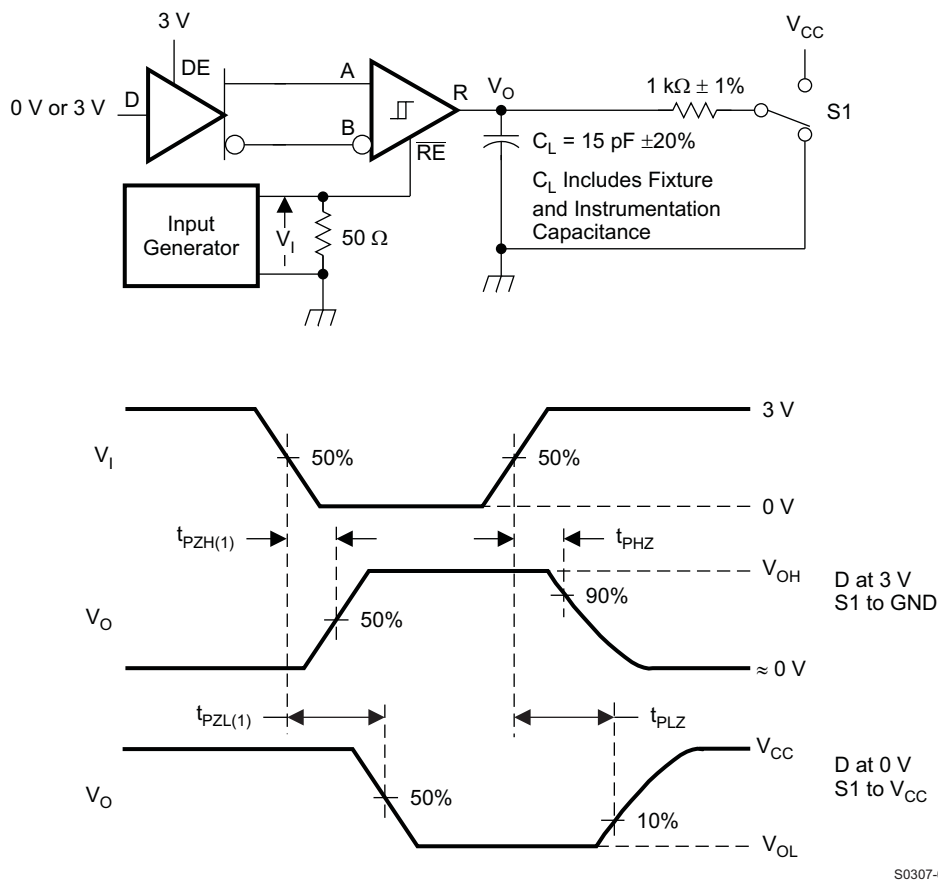


Figure 7. Measurement of Receiver Enable/Disable Times With Driver Enabled

PARAMETER MEASUREMENT INFORMATION (continued)

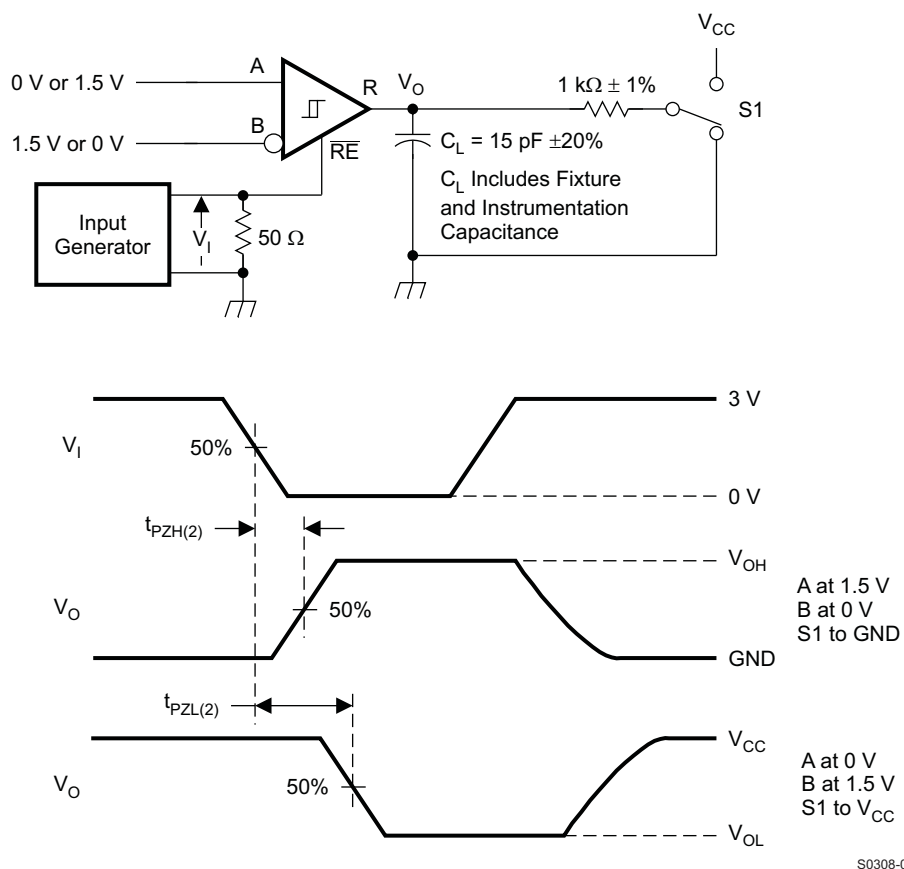


Figure 8. 'HVD1781 Measurement of Receiver Enable Times With Driver Disabled

TYPICAL CHARACTERISTICS

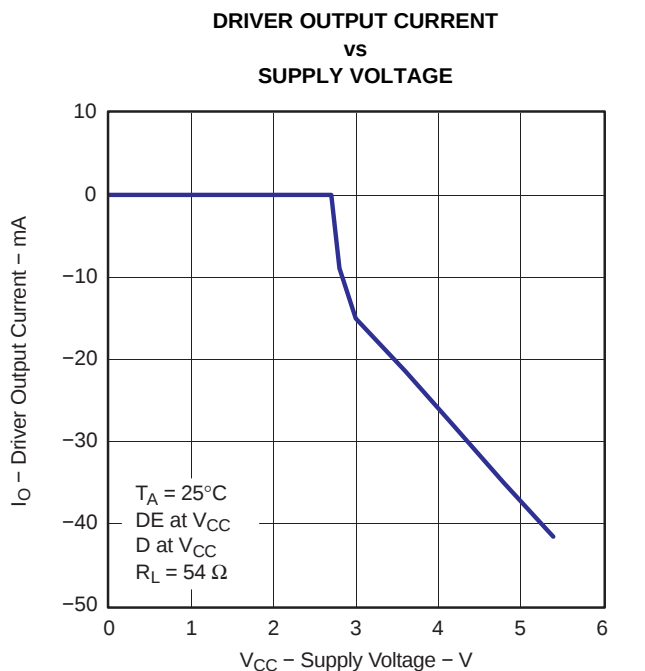


Figure 9.

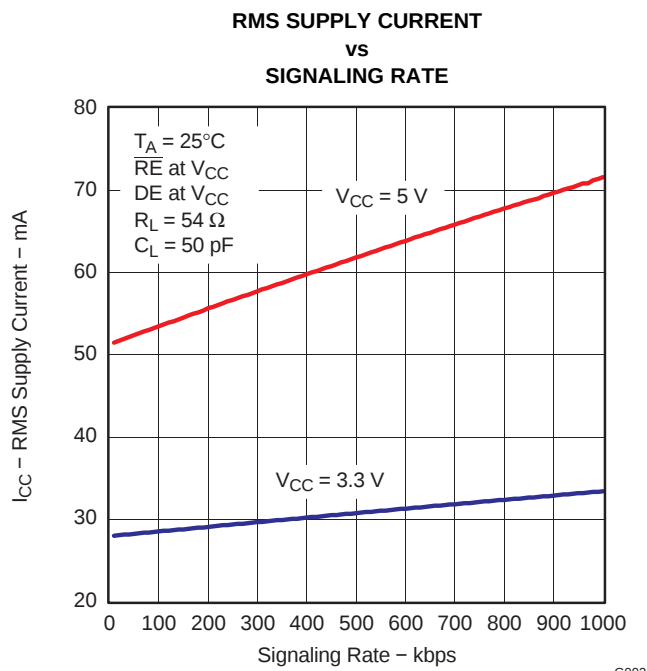


Figure 10.

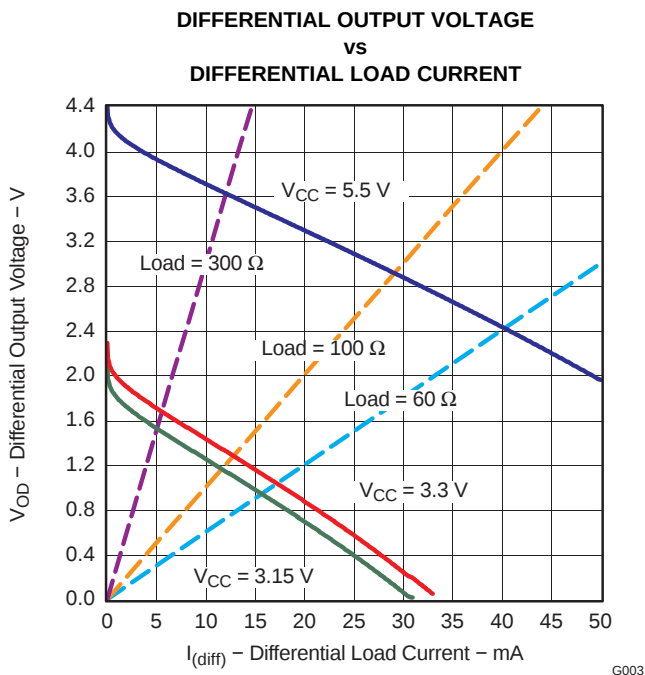


Figure 11.

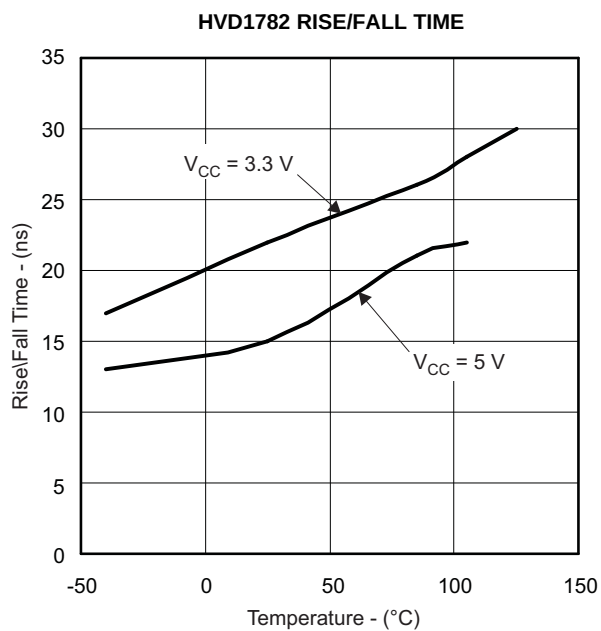


Figure 12.

TYPICAL CHARACTERISTICS (continued)
HVD1780 DIFFERENTIAL OUTPUT AMPLITUDE and TRANSITION TIME
vs
SUPPLY VOLTAGE

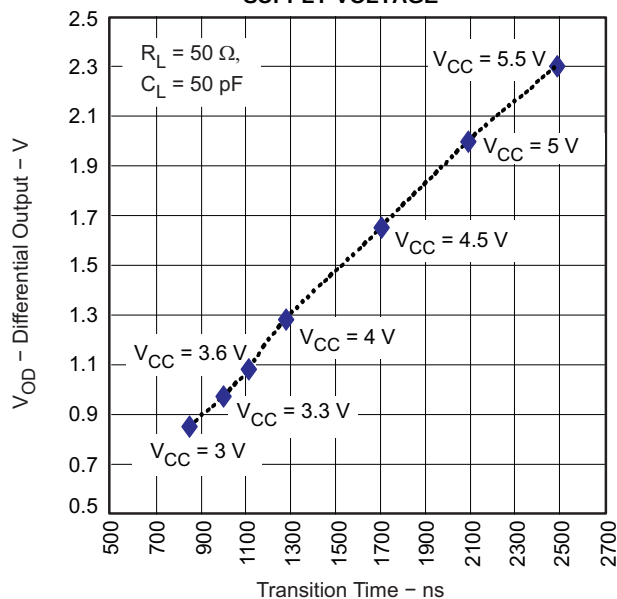


Figure 13.

70-V Fault-Protection

The SN65HVD17xx family of RS-485 devices is designed to survive bus pin faults up to $\pm 70V$. The devices designed for fast signaling rate (10 Mbps) will not survive a bus pin fault with a direct short to voltages above 30V when:

1. the device is powered on AND
 - 2a. the driver is enabled (DE=HIGH) AND D=HIGH AND the bus fault is applied to the A pin OR
 - 2b. the driver is enabled (DE=HIGH) AND D=LOW AND the bus fault is applied to the B pin

Under other conditions, the device will survive shorts to bus pin faults up to 70V. Table 1 summarizes the conditions under which the device may be damaged, and the conditions under which the device will not be damaged.

Table 1. Device Conditions

POWER	DE	D	A	B	RESULTS
OFF	X	X	$-70V < V_A < 70V$	$-70V < V_B < 70V$	Device survives
ON	LO	X	$-70V < V_A < 70V$	$-70V < V_B < 70V$	Device survives
ON	HI	L	$-70V < V_A < 70V$	$-70V < V_B < 30V$	Device survives
ON	HI	L	$-70V < V_A < 70V$	$30V < V_B$	Damage may occur
ON	HI	H	$-70V < V_A < 30V$	$-70V < V_B < 30V$	Device survives
ON	HI	H	$30V < V_A$	$-70V < V_B < 30V$	Damage may occur

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SN65HVD1781QDRQ1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN65HVD1781-Q1 :

- Catalog: [SN65HVD1781](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD1781QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

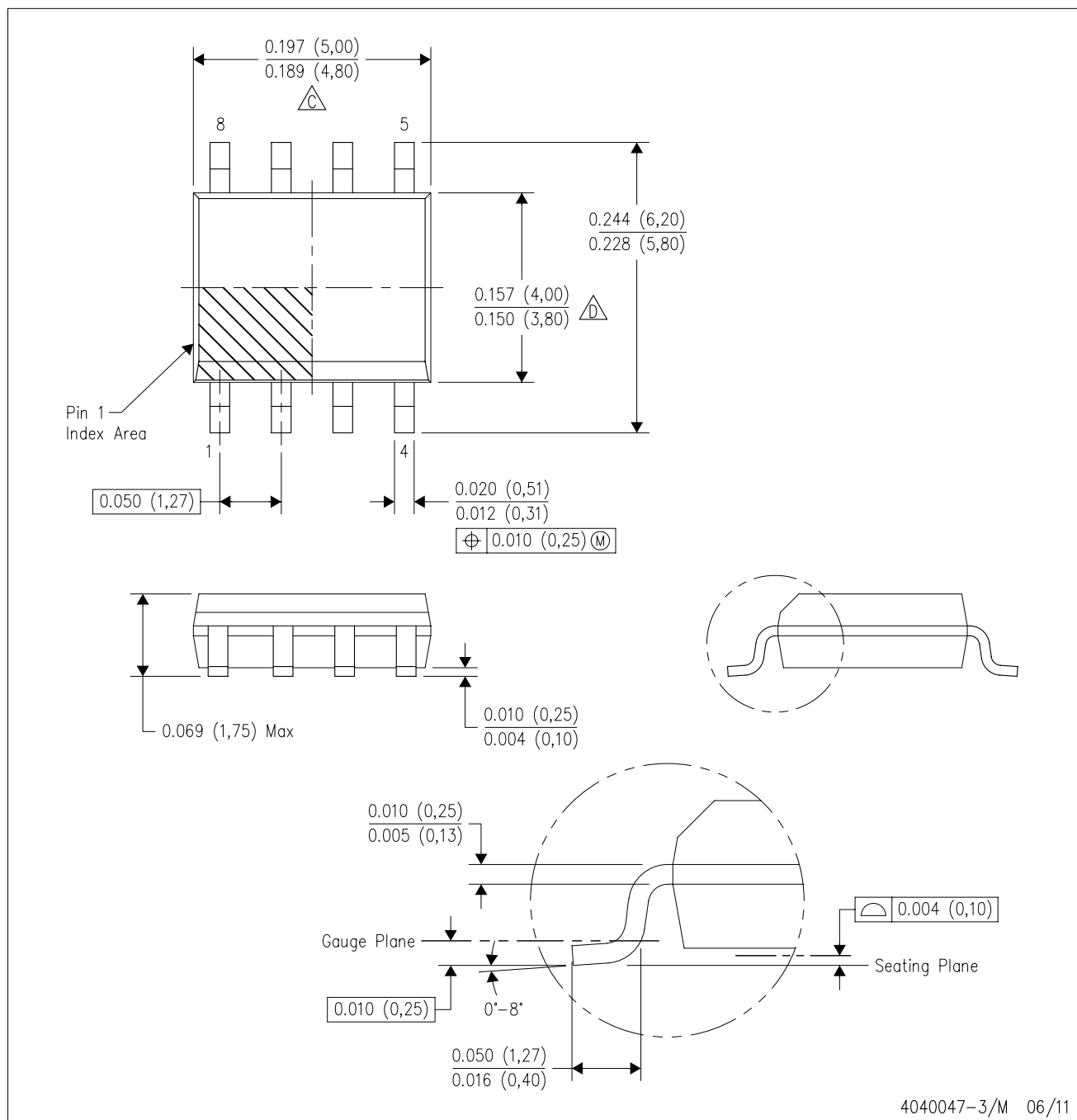


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD1781QDRQ1	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46C and to discontinue any product or service per JESD48B. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Mobile Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community e2e.ti.com